## ZNI1000 Temperature sensor

## Description

The ZNI1000 is a Ni thin film Resistance Temperature Detector (RTD), specified to DIN 43760. The high temperature coefficient offers higher signal outputs than other RTD's, which results in higher accuracy with smaller temperature changes.

### Features

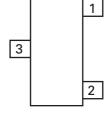
- Resistance at 0°C: 1000
- Nickel temperature detector
- Specified to DIN 43760
- SOT23 package

## Applications

- Automotive electronic
- Circuit protection
- Temperature compensation
- Temperature measurement

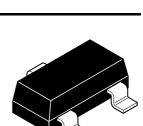
## **Ordering information**

Device	Reel size (inches)	Tape width (mm)	Quantity per reel	Device marking
ZNI1000TA	7	8	3,000	ZNI
ZNI1000TC	13	8	10,000	ZNI



Pinout - top view

Pin 1 - Ni1000 Pin 2 - Ni1000 Pin 3 - Need a good thermal contact for short response time





## Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Continuous current <sup>(a)</sup>	I <sub>CC</sub>	5	mA
Total power dissipation	P <sub>TOT</sub>	20	mW
Operating temperature range	T <sub>A</sub>	-55 to +150	°C
Storage temperature range	T <sub>stg</sub>	-55 to +150	°C

### NOTES:

(a) Limited by operating temperature [  $I_{CC}{\leq}(20mW/R)^{\frac{1}{2}}$  , R=func(T\_A)=718 to 1986\Omega].

### **Recommended operating conditions**

Symbol	Parameter	Min.	Тур.	Max.	Unit
I <sub>MDC</sub>	Steady state measurement current <sup>(b)</sup>	0,1	1,2	3,0	mA

### NOTES:

(b) limited by self heating effects (recommended current range 0,1 to 1,5mA)

[ typ. case  $\rightarrow$  temperature error  $\Delta$ T= (R·1,2mA·1,2mA)/1,7mW/K  $\leq$  1,7K ]

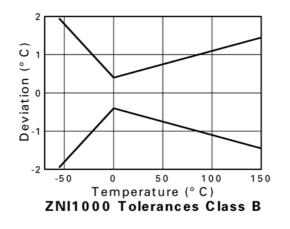
[ worst case → temperature error  $\Delta T$ = (1,986k $\Omega$ ·3,0mA·3,0mA)/1,4mW/K = 13,8K ].

### **Electrical characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
R0	Resistance 0°C	T=0°C, I <sub>M</sub> <1mA	-	1000	-	Ω
R25	Resistance 25°C	T=25°C, $I_M = 3mA^{(c)}$	1100	1141	1200	Ω
R100	Resistance 100°C	T=100°C, I <sub>M</sub> <1mA	-	1618	-	Ω
	Tolerance class B <sup>(d)</sup>	-55 to 0°C	-	±(0.4+0.028 x ¦T¦)	-	°C
	Tolerance class B <sup>(d)</sup>	0 to 150°C	-	±(0.4+0.007 x ¦T¦)	-	°C
$\Delta R$	Long Term stability:	1000h at 150°C		0.1		%

### NOTES:

(c) Measured under pulse conditions.(d) See ZNi1000 Tolerance class figure.



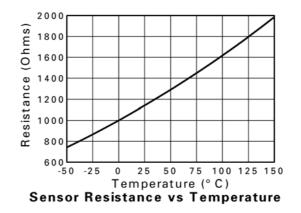
### **Characteristics according to DIN43760**

### Resistance at a given temperature

R0	Resistance at 0°C	В	6.650 x 10 <sup>-6</sup>
Т	Temperature in °C	С	2.805 x 10 <sup>-11</sup>

А	5.485 x 10 <sup>-3</sup>	D	-2.000 x 10 <sup>-17</sup>

$$R(T) = R0 \times (1 + A \times T + B \times T^{2} + C \times T^{4} + D \times T^{6})$$



### Formula for temperature at a given resistance

 $T(R) = A + B \times \sqrt{1 + C \times R} + D \times R^{5} + E \times R^{7}$ coefficients: A = -412.6B = 140.41C = 0.00764 $D = -6.25 \times 10^{-17}$  $E = -1.25 \times 10^{-24}$ 

### Self heating

For accurate temperature measurement it's recommended to choose a small current in order to avoid self heating of the resistor. The temperature failure caused by the measurement current can be calculated with:

$$\Delta \mathsf{T}=\mathsf{P}/\mathsf{E}\mathsf{K}$$

where  $P = I^2 * R$  is the heat power caused by the measurement current and EK is the self heating coefficient.

The self heating coefficient for the Ni1000-SOT is:

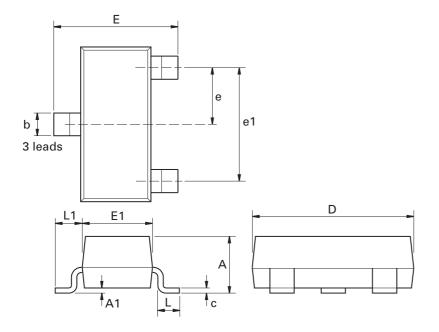
 $EK = (1.7 \pm 0.3) \text{ mW/K}$  (Air: 23°C; no air flow).

₽° C | DVM 1V-->100'C 0,2V-->20'C 0 Application of the nickel sensor ZNI 1000 500 680 1,5k ≒ 11 100n OUT 1,5k ZMR500 (5V) GND +ZNI1000 t° Ζ (1k) 10u + 100n

# ZNI1000

+15V

## Package outline - SOT23



Dim.	Millin	neters	Inc	hes	Dim.	Millin	neters	Inc	hes
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
А	-	1.12	-	0.044	e1	1.90	NOM	0.075	NOM
A1	0.01	0.10	0.0004	0.004	E	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
С	0.085	0.20	0.003	0.008	L	0.25	0.60	0.0098	0.0236
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
е	0.95	NOM	0.037	NOM	-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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